Vishay Semiconductors

Optocoupler, Phototransistor Output, AC Input, with Base Connection

FEATURES

- Guaranteed CTR symmetry, 2:1 maximum
- Bidirectional AC input industry standard SOIC-8 Surface mountable package
- Isolation test voltage, 4000 V_{BMS}
- Standard lead spacing, 0.05"
- Available only on tape and reel (conform to EIA standard RS481A)
- · Lead (Pb)-free component
- · Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

Telecom applications ring detection

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- CUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) available with option 1

ORDER INFORMATION	
PART	REMARKS
IL256AT	CTR > 20 %, tape and reel, SOIC-8

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT		•		
Forward continuous current		I _F	60	mA
Power dissipation		P _{diss}	90	mW
Derate linearly from 25 °C			0.8	mW/°C
OUTPUT		•		
Collector-emitter breakdown voltage		BV _{CEO}	30	V
Emitter-collector breakdown voltage		BV _{ECO}	5	V
Collector-base breakdown voltage		BV _{CBO}	70	V
Power dissipation		P _{diss}	150	mW
Derate linearly from 25 °C			2.0	mW/°C
COUPLER		•		
Isolation voltage, input to output		V _{ISO}	4000	V _{RMS}
Total package dissipation (LED and detector)		P _{tot}	240	mW
Derate linearly from 25 °C			3.2	mW/°C
Storage temperature		T _{stg}	- 55 to + 150	°C
Operating temperature		T _{amb}	- 55 to + 100	°C
Soldering time at 260 °C			10	S

Note

 T_{amb} = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.







i179025

DESCRIPTION

SOIC-8 foot print.

minimum of 20 % at $I_F = 10$ mA.

detector.

A/C 1

C/A 2

NC 3

NC 4

The IL256AT is an AC input phototransistor optocoupler. The device consists of two infrared emitters connected in reverse

parallel and coupled to a silicon NPN phototransistor

These circuit elements are constructed with a standard

The product is well suited for telecom applications such as

ring detection or off/on hook status, given its bidirectional

LED input and guaranteed current transfer ratio (CTR)

8 NC

7 B

6 C

5 E

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ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	$I_F = \pm 10 \text{ mA}$	VF		1.2	1.5	V	
OUTPUT				•	•		
Collector emitter breakdown voltage	I _C = 1.0 mA	BV _{CEO}	30	50		V	
Emitter collector breakdown voltage	I _E = 100 μA	BV _{ECO}	5	10		V	
Collector base breakdown voltage	I _C = 100 μA	BV _{CBO}	70	90		V	
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}		5	50	nA	
COUPLER				•	•	•	
Saturation voltage, collector emitter	$I_F = 16 \text{ mA}, I_C = 2 \text{ mA}$	V _{CEsat}			0.4	V	

Note

 T_{amb} = 25 °C, unless otherwise specified. Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	I _F = 10 mA, V _{CE} = 5 V	CTR _{DC}	20			%
Symmetry (CTR at + 10 mA)/(CTR at -10 mA)			0.5	1	2	

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V _{IOTM}			6000			V
VIORM			560			V
PSO					350	mW
ISI					150	mA
TSI					165	°C
Creepage distance			4			mm
Clearance distance			4			mm
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.2			mm

Note

As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of prodective circuits.



Optocoupler, Phototransistor Output, Vishay Semiconductors AC Input, with Base Connection

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified



Fig. 1 - LED Forward Current vs.Forward Voltage



Fig. 2 - Forward Voltage vs. Forward Current



Fig. 3 - Peak LED Current vs. Duty Factor, Tau



Fig. 4 - Normalized CTR vs. I_F and T_{amb}



Fig. 5 - Normalized Saturated CTR



Fig. 6 - Normalized CTRcb

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Fig. 7 - Photocurrent vs. LED Current



Fig. 8 - Base Current vs. I_{F} and h_{FE}



Fig. 9 - Normalized h_{FE} vs. Base Current and Temp.



Fig. 10 - Normalized Saturated $h_{\text{FE}}\, vs.$ Base Current



Fig. 11 - Base Emitter Voltage vs. Base Current



Fig. 12 - Collector-Emitter Leakage Current vs.Temp.



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PACKAGE DIMENSIONS in inches (millimeters)



i178020

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OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.З, офис 1107

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